



### USB 3.2 Gen 2x2 ReDriver

## Features

- 5Gbps & 10Gbps Serial Link with Linear Equalizer
- USB 3.2 Gen 2 and Gen 1 Compatible
- USB 3.2 Gen 2x2 Compatible
- Four 10Gbps Differential Signal Pairs
- Pin Adjustable Receiver Equalization
- Pin Adjustable Flat Gain
- 100Ω Differential CML I/Os
- Automatic Receiver Detect
- Auto Slumber Mode for Adaptive Power Management
- Single Supply Voltage: 3.3V
- Patented Technology
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.

https://www.diodes.com/quality/product-definitions/

- Packaging (Pb-free & Green available):
  - <sup>o</sup> 34-pin, UQFN 2.5mm × 4.5mm (ZTF34)

# Description

The PI3EQX2024 is a low-power, high-performance, USB 3.2 Gen 2x2 linear ReDriver<sup>™</sup> designed specifically for the USB 3.2 protocol.

The device provides programmable equalization and flat gain to optimize performance over a variety of physical mediums by reducing intersymbol interference. PI3EQX2024 supports two  $100\Omega$  differential CML data I/Os between the Protocol ASIC to a switch fabric, over cable, or to extend the signals across other distant data pathways on the user's platform.

The integrated equalization circuitry provides flexibility with signal integrity of the signal before the ReDriver. Each channel operates fully independently. The channels' input signal level determines whether the output is active.

The PI3EQX2024 also includes an automatic receiver detect function. The receiver detection loop is active again if the corresponding channel's signal detector is idle for longer than 7.3ms. The channel then moves to unplug mode if load is not detected, or it returns to low-power mode (slumber mode) due to inactivity.



Notes:

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

ReDriver is a trademark of Diodes Incorporated. PI3EQX2024 Document Number DS43042 Rev 2-2

<sup>1.</sup> No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.





## **Block Diagram**







# **Pin Configuration**



# **Pin Description**

| Pin #                            | Pin Name   | Туре                                   | Description   |  |
|----------------------------------|------------|--|---|--|
| 13, 17, 30, 34                   | VDD        | Power                                  | 3.3V power supply, ±0.3V  |  |
| 32, 23                           | FGA, FGB   | Innut                                  | The DC flat gain selection. 4-level input pins. With internal 100k $\Omega$ pullup resistor |  |
| 6, 15                            | FGC, FGD   | Input                                  | and $200 \mathrm{k}\Omega$ pulldown resistor.   |  |
| 31, 24                           | EQA, EQB   | Innut                                  | The EQ selection. 4-level input pins. With internal 100k $\Omega$ pullup resistor and       |  |
| 7, 14                            | EQC, EQD   | Input                                  | 200k $\Omega$ pulldown resistor.  |  |
| 1, 2                             | RXAP, RXAN |  |   |  |
| 25, 26                           | RXBP, RXBN | Innut                                  | CML input terminals. With selectable input termination between 50 $\Omega$ to VDD,          |  |
| 8,9                              | RXCP, RXCN | Input                                  | 270k $\Omega$ to VbiasRx, or 67k $\Omega$ to GND.   |  |
| 18, 19                           | RXDP, RXDN |  |   |  |
| 29, 28                           | TXAP, TXAN |  |   |  |
| 5, 4                             | TXBP, TXBN | Quatarat                               | CML output terminals. With selectable output termination between 50 $\Omega$ to             |  |
| 22, 21                           | TXCP, TXCN | Output                                 | VDD, $6k\Omega$ to VDD, $6k\Omega$ to VbiasTx or $67k\Omega$ to GND.                        |  |
| 12, 11                           | TXDP, TXDN |  |   |  |
|                                  |            |  | Channel Enable. With internal 300k $\Omega$ pullup resistor.                                |  |
| 33                               | EN         | Input                                  | "High" – Channel is in normal operation.  |  |
| "Low" – Channel is in power down |            | "Low" – Channel is in power down mode. |   |  |
| 16                               | CAP_EXT    | I/O                                    | Decoupling Capacitor for Internal Bias.   |  |
| 3, 10, 20, 27,<br>Center Pad     | GND        | GND                                    | Supply Ground   |  |





### **Power Management**

Notebooks, netbooks, and other power sensitive consumer devices require judicious use of power in order to maximize battery life. In order to minimize the power consumption of our devices, Diodes added an additional adaptive power management feature. When a signal detector is idle for longer than 1.3ms, the corresponding channel moves to low-power mode ONLY, which means both channels move to low-power mode individually.

In low-power mode, the signal detector continues monitoring the input channel. If a channel is in low-power mode and the input signal is detected, the corresponding channel wakes up immediately. If a channel is in low-power mode and the signal detector is idle longer than 6ms, the receiver detection loop is active again. If load is not detected, then the channel moves to device unplug mode and monitors the load continuously. If load is detected, it returns to low-power mode, and receiver detection is active again per 6ms.

#### **Operating Modes**

| Mode              | R <sub>IN</sub>              | R <sub>OUT</sub>             |
|-------------------|------------------------------|------------------------------|
| PD                | $67 \mathrm{k}\Omega$ to GND | $67 \mathrm{k}\Omega$ to GND |
| Unplug Mode       | 270k $\Omega$ to VbiasRx     | $6k\Omega$ to VbiasTx        |
| Deep Slumber Mode | $50\Omega$ to Vdd            | $6 k\Omega$ to VbiasTx       |
| Slumber Mode      | $50\Omega$ to Vdd            | $6k\Omega$ to Vdd            |
| Active Mode       | $50\Omega$ to Vdd            | $50\Omega$ to Vdd            |





# **Equalization Setting:**

EQA/B/C/D are the selection pins for the equalization selection.

|                            | Equalizer S | ettings (dB) |
|----------------------------|-------------|--------------|
| EQA/B/C/D                  | @ 2.5GHz    | (a) 5GHz     |
| 0 (Tie 1K $\Omega$ to GND) | 6.7         | 12.4         |
| R (Tie 68KΩ to GND)        | 3.5         | 8.0          |
| F (Leave Open)             | 5.3         | 10.6         |
| 1 (Tie 1K $\Omega$ to VDD) | 8.4         | 14.6         |

# Flat Gain Setting:

FGA/B/C/D are the selection pins for the DC gain.

|                            | Flat Gain Settings |
|----------------------------|--------------------|
| FGA/B/C/D                  | dB                 |
| 0 (Tie 1K $\Omega$ to GND) | -1.6               |
| R (Tie 68KΩ to GND)        | -0.5               |
| F (Leave Open)             | 1.0                |
| 1 (Tie 1K $\Omega$ to VDD) | 2.7                |

### **Channel Enable Setting:**

|    | Channel Enable Settings |
|----|-------------------------|
| EN | Setting                 |
| 0  | Disabled                |
| 1  | Enabled (Default)       |





# **Maximum Ratings**

| Above which useful life may be impaired. | For user guidelines, not tested.) |
|--|-----------------------------------|
| Storage Temperature                      | 65°C to +150°C                    |
| Supply Voltage to Ground Potential       | -0.5V to +3.8V                    |
| DC SIG Voltage                           | 0.5V to V <sub>DD</sub> + $0.5V$  |
| Output Current                           | 25mA to +25mA                     |
| ESD, Human Body Model                    |                                   |
| Power Dissipation Continuous             |                                   |
| Max Junction Temperature                 |                                   |
|  |                                   |

#### Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

### **Control Pin Specifications** (VDD = $3.3 \pm 0.3$ V, TA = -40 to 85°C)

| Symbol            | Parameter                               | Min.                     | Тур.                     | Max.                     | Units |
|-------------------|---|--------------------------|--------------------------|--------------------------|-------|
| 2-Level Control P | lins                                    |                          |                          |                          |       |
| V <sub>IH</sub>   | DC Input Logic High                     | $VDD \times 0.65$        | _                        | —                        | V     |
| V <sub>IL</sub>   | DC Input Logic Low                      | _                        | _                        | $VDD \times 0.35$        | V     |
| I <sub>IH</sub>   | Input High Current                      |                          | _                        | 25                       | μΑ    |
| I <sub>IL</sub>   | Input Low Current                       | -25                      | _                        |                          | μΑ    |
| 4-Level Control P | Pins                                    |                          |                          |                          |       |
| V <sub>IH</sub>   | DC Input Logic "High"                   | $0.92 \times \text{VDD}$ | VDD                      | —                        | V     |
| V <sub>IF</sub>   | DC Input Logic "Float"                  | $0.59 \times \text{VDD}$ | $0.67 \times \text{VDD}$ | $0.75 \times \text{VDD}$ | V     |
| V <sub>IR</sub>   | DC Input Logic "With Rext to GND"       | $0.25 \times \text{VDD}$ | $0.33 \times \text{VDD}$ | $0.41 \times \text{VDD}$ | V     |
| V <sub>IL</sub>   | DC Input Logic "Low"                    | _                        | GND                      | $0.08 \times \text{VDD}$ | V     |
| I <sub>IH</sub>   | Input High Current                      | _                        | _                        | 50                       | μΑ    |
| I <sub>IL</sub>   | Input Low Current                       | -50                      | _                        | _                        | μΑ    |
| Rext              | External Resistor Connects to GND (±5%) | 64.6                     | 68                       | 71.4                     | kΩ    |

### AC/DC Electrical Characteristics (VDD = $3.3 \pm 0.3$ V TA = -40 to $85^{\circ}$ C)

| Symbol                   | Parameter                                | Conditions  | Min. | Тур. | Max. | Units |
|--------------------------|--|---|------|------|------|-------|
| Power and Latency        |  |   |      |      |      |       |
| V <sub>dd-3.3</sub>      | Supply Voltage                           |   | 3.0  | 3.3  | 3.6  | V     |
| I <sub>active</sub>      | Active Mode Current Consumption          | EN = 1, 10Gbps, compliance test pat-<br>tern                | _    | 260  | 334  | mA    |
| I <sub>slumber</sub>     | Slumber Mode Current Consumption         | EN = 1, no input signal longer than<br>T <sub>slumber</sub> | _    | 32   | 38   |       |
| I <sub>DeepSlumber</sub> | Deep Slumber Mode Current<br>Consumption | $EN = 1$ no input signal longer than $T_{DeepSlumber}$      | _    | 0.8  | 1.2  | mA    |
| Iunplug                  | Unplug Mode Current Consumption          | EN = 1, no output load is detected                          | _    | 0.6  | 0.9  |       |
| I <sub>pd</sub>          | Power Down Mode Current<br>Consumption   | EN = 0  | _    | 20   | 120  | μΑ    |
| t <sub>pd</sub>          | Latency                                  | From input to output  |      | _    | 2    | ns    |





### AC/DC Electrical Characteristics Cont.

| Symbol                            | Parameter   | Conditions   | Min.  | Тур. | Max.  | Units   |
|-----------------------------------|---|--|-------|------|-------|---------|
| CML Receiver In                   | put (100 $\Omega$ Differential)   | l  |       |      |       | ,       |
| Receiver Electrica                | ll Specification  |  |       |      |       |         |
| Crxparasitic                      | The Parasitic Capacitor for RX  | _  | _     |      | 1.0   | pF      |
| R <sub>RX-DIFF-DC</sub>           | DC Differential Input Impedance   | _  | 72    | _    | 120   |         |
| R <sub>RX-SINGLE_DC</sub>         | DC Single Ended Input Impedance   | DC impedance limits are need to guar-<br>antee RxDet. Measured with respect to<br>GND over a voltage of 500mV max. | 18    |      | 30    | Ω       |
| Z <sub>RX-HIZ-DC-PD</sub>         | DC Input CM Input Impedance for<br>V>0 During Reset or Power Down   | (Vcm=0 to 500mV)   | 25    | —    | _     | kΩ      |
| Cac_coupling                      | AC Coupling Capacitance   | —  | 75    | —    | 265   | nF      |
| V <sub>RX-CM-AC-P</sub>           | Common Mode Peak Voltage  | AC up to 5GHz  | _     | _    | 150   | mVpeak  |
| VRX-CM-DC-Active-<br>Idle-Delta-P | Common Mode Peak Voltage<br> Avguo( V <sub>TX-D+</sub> + V <sub>TX-D-</sub>  )/2-Avgu1( V <sub>TX-D+</sub> +<br>V <sub>TX-D-</sub>  )/2   | Between U0 and U1. AC up to 5GHz   |       | _    | 200   | mVpeak  |
| Transmitter Elec                  | trical Specification  | •  |       |      |       |         |
| V <sub>TX-DIFF-PP</sub>           | Output Differential p-p Voltage Swing   | Differential Swing  V <sub>TX-D+</sub> -V <sub>TX-D-</sub>   | _     | _    | 1.2   | Vppd    |
| R <sub>TX-DIFF-DC</sub>           | DC Differential TX Impedance  | _  | 72    | _    | 120   | Ω       |
| VTX-RCV-DET                       | The Amount of Voltage Change<br>Allowed During RxDet  | _  | _     | _    | 600   | mV      |
| Cac_coupling                      | AC Coupling Capacitance   | -  | 75    | _    | 265   | nF      |
| T <sub>TX-EYE</sub> (10Gbps)      | Transmitter Eye, Include all Jitter   | At the silicon pad. 10Gbps   | 0.646 | —    | —     | UI      |
| T <sub>TX-EYE</sub> (5Gbps)       | Transmitter Eye, Include all Jitter   | At the silicon pad. 5Gbps  | 0.625 | —    | —     | UI      |
| T <sub>TX</sub> -DJ-DD(10Gbps)    | Transmitter Deterministic Jitter  | At the silicon pad. 10Gbps   | _     | —    | 0.17  | UI      |
| T <sub>TX-DJ-DD(5Gbps)</sub>      | Transmitter Deterministic Jitter  | At the silicon pad. 5Gbps  | —     | —    | 0.205 | UI      |
| C <sub>txparasitic</sub>          | The Parasitic Capacitor for TX  | —  | —     | —    | 1.1   | pF      |
| R <sub>TX-DC-CM</sub>             | Common mode DC Output<br>Impedance  | _  | 18    | _    | 30    | Ω       |
|                                   | The Instantaneous Allowed DC  | Min1 is with 200k $\Omega$ single ended receiver load respectively.  | -0.5  |      | 1     |         |
| VTX-DC-CM                         | Side of the AC Coupling Capacitors  | Min2 is with $50\Omega$ single ended receiver load respectively.   | -0.3  |      | 1     |         |
| V <sub>TX-C</sub>                 | Common-Mode Voltage   | V <sub>TX-D+</sub> +V <sub>TX-D-</sub>  /2   | VDD-2 | _    | VDD   | V       |
| VTX-CM-AC-PP-<br>Active           | Active Mode TX AC Common Mode<br>Voltage  | $V_{TX-D+}+V_{TX-D-}$ for both time and amplitude  | _     |      | 100   | mVpp    |
| VTX-CM-DC-<br>Active_Idle-Delta   | Common Mode Delta Voltage<br> Avguo( V <sub>TEX-D+</sub> + V <sub>TX-D-</sub> ])/2-Avgu1( V <sub>TX-D+</sub><br>+ V <sub>TX-D-</sub> ])/2 | Between U0 to U1   | _     |      | 200   | mV-peak |





### AC/DC Electrical Characteristics Cont.

| Symbol                           | Parameter   | Conditions  | Min. | Тур. | Max. | Units             |
|----------------------------------|---|---|------|------|------|-------------------|
| V <sub>TX</sub> -Idle-Diff-AC-pp | Idle Mode AC Common Mode Delta<br>Voltage  V <sub>TX-D+</sub> -V <sub>TX-D-</sub> | Between Tx+ and Tx- in idle mode. Use<br>the HPF to remove DC components.<br>=1/LPF. No AC and DC signals are<br>applied to Rx terminals. |      | _    | 10   | mVppd             |
| V <sub>TX-Idle</sub> -Diff-DC    | Idle Mode DC Common Mode Delta<br>Voltage  V <sub>TX-D+</sub> -V <sub>TX-D-</sub> | Between Tx+ and Tx- in idle mode. Use<br>the LPF to remove DC components.<br>=1/HPF. No AC and DC signals are<br>applied to Rx terminals. | _    | _    | 10   | mV                |
| Channel Perform                  | nance   |   |      |      |      |                   |
|                                  |   | EQx=0   |      | 12.4 |      |                   |
|                                  | Peaking Gain (Compensation at 5GHz.   | EQx=R   | _    | 8.0  |      | dB                |
| Gp                               | Relative to 100MHz, 100mV <sub>p-p</sub> Sine                                     | EQx=F   |      | 10.6 |      | dB                |
|                                  | Wave Input)   | EQx=1   |      | 14.6 |      |                   |
|                                  |   | Variation around typical  | -3   | —    | +3   | dB                |
|                                  | Flat Gain (100MHz, EQx=F)   | FQx=0   |      | -1.6 |      |                   |
| G <sub>F</sub>                   |   | FQx=R   |      | -0.5 |      | ۹۲                |
|                                  |   | FQx=F   | —    | 1.0  |      | dБ                |
|                                  |   | FQx=1   |      | 2.7  |      |                   |
|                                  |   | Variation around typical  | -3   | _    | +3   | dB                |
| V <sub>SW_100M</sub>             | -1dB Compression Point Output Swing<br>(at 100MHz)                                | _   |      | 1000 | _    | mVppd             |
| V <sub>SW_5G</sub>               | -1dB Compression Point Output Swing<br>(at 5GHz)                                  | _   | —    | 850  | _    | mVppd             |
| DDNEXT                           | Differential Near-End Crosstalk <sup>(1)</sup>                                    | 100MHz to 5GHz, Figure 2  | —    | -40  | —    | dB                |
| 17                               |   | 100MHz to 5GHz, FGx=1, EQx=R,<br>Figure 5   | —    | 0.6  | _    |                   |
| Vnoise-input                     | Input-Referred Noise  | 100MHz to 5GHz, FGx=1, EQx=1,<br>Figure 5   | _    | 0.5  | _    | mv <sub>RMS</sub> |
|                                  | 2 D. (  | 100MHz to 5GHz, FGx=1, EQx=R,<br>Figure 5   | _    | 0.8  | _    |                   |
| V <sub>noise-output</sub>        | Output-Referred Noise <sup>(2)</sup>  | 100MHz to 5GHz, FGx=1, EQx=1,<br>Figure 5   |      | 1    | _    | mV <sub>RMS</sub> |
| Signal and Frequ                 | ency Detectors  |   |      |      |      |                   |
| V <sub>th_upm</sub>              | Unplug Mode Detector Threshold  | Threshold of LFPS when the input impedance of the redriver is $67k\Omega$ to VbiasRx only. Used in the unplug mode.                       | 200  | _    | 800  | mVppd             |
| V <sub>th_dsm</sub>              | Deep Slumber Mode Detector Threshold  | LFPS signal threshold in deep slumber mode  | 100  | _    | 600  | mVppd             |





## AC/DC Electrical Characteristics Cont.

| Symbol                              | Parameter   | Conditions                                    | Min. | Тур. | Max. | Units |
|-------------------------------------|---|---|------|------|------|-------|
| V <sub>th_am</sub>                  | Active Mode Detector Threshold                      | Signal threshold in active and slumber mode   | 45   | _    | 175  | mVppd |
| F <sub>th</sub>                     | LFPS Frequency Detector                             | Detect the frequency of the input CLK pattern | 100  |      | 400  | MHz   |
| External Decoupling Capacitor value |   |   |      |      |      |       |
| CAP_EXT                             | External decoupling capacitor for the internal bias |   | 2.2  |      | 20   | uF    |

Note:

1. Measured using a vector-network analyzer (VNA) with -15dBm power level applied to the adjacent input. The VNA detects the signal at the output of the victim channel. All other inputs and outputs are terminated with  $50\Omega$ .

2. Guaranteed by design and characterization.

### Power-up/Power-down Timing and VCM Ramp Rate



# Figure 2. Power-up Timing

### **Power-up Timing**

| Symbol            | Parameter                                      | Condition | Min. | Тур. | Max. | Units |
|-------------------|--|-----------|------|------|------|-------|
| T <sub>d_EN</sub> | VDD3P3 to EN assertion delay time              |           | 0    |      |      | ms    |
| T <sub>VCM</sub>  | Stabilization time for VCM common mode voltage |           |      | 330  | 400  | ms    |



## Figure 3. Power-down Timing

# **Power-down Timing**

| Symbol             | Parameter   | Condition | Min. | Тур. | Max. | Units |
|--------------------|---|-----------|------|------|------|-------|
| T <sub>d_OFF</sub> | Delay time from EN de-assertion to VDD3P3 power off |           | 900  |      |      | ms    |







Figure 4. Channel-Isolation Test Configuration



**Figure 5. Noise Test Configuration** 



Figure 6. Test Condition Referenced in the Electrical Characteristic Table





# **Part Marking**







# **Packaging Mechanical**





#### For latest package information:

See http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/.

# **Ordering Information**

| Ordering Number | Package Code | Package Description                             |
|-----------------|--------------|---|
| PI3EQX2024ZTFEX | ZTF          | 34-Contact, Ultra Thin Quad Flat No-Lead (UQFN) |
|                 |              |   |

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. E = Pb-free and Green

5. X suffix = Tape/Reel





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